**Vishay Semiconductors** 

High Performance Schottky Rectifier, 3.0 A



www.vishay.com



DO-214AB (SMC)

PRODUCT SUMMARY				
Package	SMC			
I <sub>F(AV)</sub>	3.0 A			
V <sub>R</sub>	60 V			
V <sub>F</sub> at I <sub>F</sub>	0.61 V			
I <sub>RM</sub> max.	30 mA at 125 °C			
T <sub>J</sub> max.	150 °C			
Diode variation	Single die			
E <sub>AS</sub>	5.0 mJ			

### **FEATURES**

- · Small foot print, surface mountable
- · Very low forward voltage drop
- High frequency operation



- · Guard ring for enhanced ruggedness and long FREE term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

## DESCRIPTION

The VS-MBRS360-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES UNIT				
I <sub>F(AV)</sub>	Rectangular waveform	3.0	A			
V <sub>RRM</sub>		60	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	790	A			
V <sub>F</sub>	3.0 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.61	V			
TJ	Range	-55 to +150	°C			

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-MBRS360-M3	UNITS	
Maximum DC reverse voltage	V <sub>R</sub>	60	V	
Maximum working peak reverse voltage	V <sub>RWM</sub>	00	v	

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum avarage ferward autrent	1	50 % duty cycle at $T_L$ = 118 °C, rectangular waveform		3.0		
Maximum average forward current	IF(AV)	50 % duty cycle at $T_L$ = 105 °C, rectangular waveform		4.0		
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	790	A	
non-repetitive surge current	IFSM	10 ms sine or 6 ms rect. pulse	$V_{\text{RRM}}$ applied	80		
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.0 A, L = 10 mH		5.0	mJ	
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		1.0	A	

Revision: 26-Aug-14 Document Number: 95749 1 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



## Vishay Semiconductors

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONE	DITIONS	TYP.	MAX.	UNITS
		3 A	т ос «О	0.57	0.74	V
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	6 A	T <sub>J</sub> = 25 °C	0.72	0.9	
Maximum forward voltage drop	VFM (*)	3 A	T <sub>J</sub> = 125 °C	0.51	0.61	
		6 A		0.62	0.77	
		T <sub>J</sub> = 25 °C		-	0.5	
Maximum reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	$T_J = 100 \ ^\circ C$	$V_R$ = Rated $V_R$	-	20	mA
		T <sub>J</sub> = 125 °C		-	30	
Maximum junction capacitance	CT	$V_{\rm R}$ = 5 $V_{\rm DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		-	180	pF
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body		-	3.0	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub> - 10		10 000	V/µs	

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

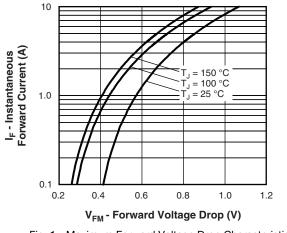
THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		-55 to +150	°C	
Maximum thermal resistance, junction to lead	R <sub>thJL</sub> <sup>(2)</sup>		12	°C/W	
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>	DC operation	46	C/W	
Approvimate weight			0.24	g	
Approximate weight			0.008	oz.	
Marking device		Case style SMC (similar to DO-214AB) 36		6	

### Notes

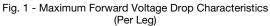
 $^{(1)} \quad \frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$ 

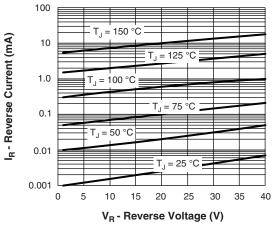
(2) Mounted 1" square PCB

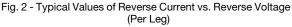
## **Vishay Semiconductors**



www.vishay.com







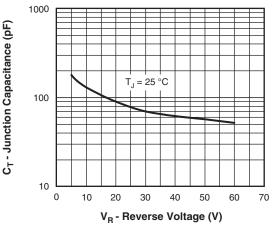


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

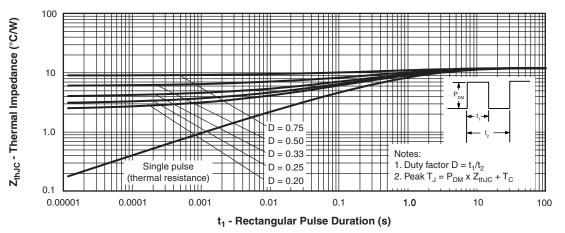


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)



D = 0.20

D = 0.25

D = 0.33

D = 0.50

D = 0.75

DC

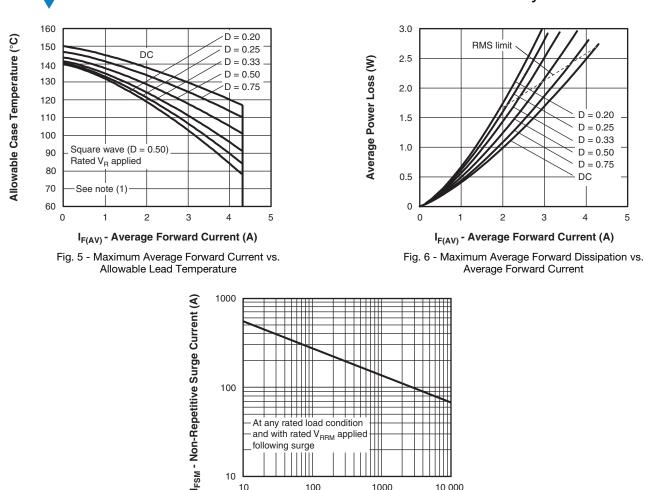
4

5

2

3

## **Vishay Semiconductors**



100

10 10

At any rated load condition and with rated  $V_{RRM}$  applied

100

following surge

t<sub>p</sub> - Square Wave Pulse Duration (μs) Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

1000

10 000

#### Note

ISHAY

www.vishay.com

```
<sup>(1)</sup> Formula used: T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC};
  \begin{array}{l} \mathsf{Pd} = \mathsf{Forward power loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \; at \; (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \; (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse power loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \; (1 - \mathsf{D}); \; \mathsf{I}_{\mathsf{R}} \; at \; \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \; \% \; \mathsf{rated} \; \mathsf{V}_{\mathsf{R}} \end{array}
```

# VS-MBRS360-M3



and termination lead (Pb)-free

www.vishay.com

### **ORDERING INFORMATION TABLE**

Device code	VS-	MBR	S	3	60	-M3	
	1	2	3	4	5	6	
	1 · 2 ·		,	niconduo BR serie		oducts	
	3 -	- S =	SMC				
	4	Cur	rent rati	ng (3 = :	3 A)		
	5 -	Volt	tage rati	ng (60 =	= 60 V)		
	6 -	M3	s = halog	gen-free	, RoHS-	-complian	ıt,

ORDERING INFORMATION (Example)					
PREFERRED P/N	PREFERRED PACKAGE CODE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-MBRS360-M3/9AT	9AT	3500	13" diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS			
Dimensions www.vishay.com/doc?95402			
Part marking information	www.vishay.com/doc?95403		
Packaging information	www.vishay.com/doc?95404		

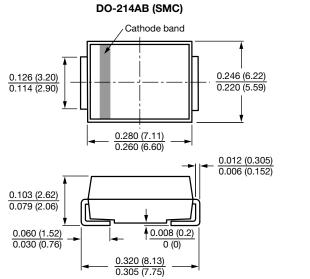


## **Outline Dimensions**

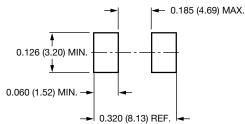
**Vishay Semiconductors** 

SMC

### **DIMENSIONS** in inches (millimeters)



Mounting Pad Layout





Vishay

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

# **Material Category Policy**

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.